

Dual 1 Form A Solid State Relay

Features

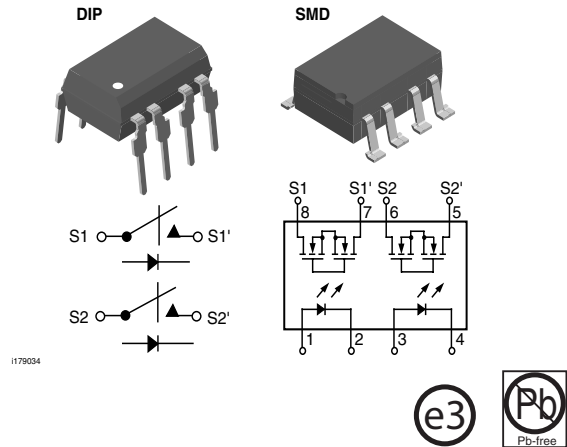
- Dual Channel (LH1540)
- Current Limit Protection
- Isolation Test Voltage 5300 V_{RMS}
- Typical R_{ON} 20 Ω
- Load Voltage 350 V
- High Surge Capability
- Clean Bounce Free Switching
- Low Power Consumption
- SMD Lead Available on Tape and Reel
- Lead-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

Agency Approvals

- UL1577, File No. E52744 System Code H or J, Double Protection
- CSA - Certification 093751
- BSI/BABT Cert. No. 7980
- DIN EN 60747-5-2 (VDE0884)
DIN EN 60747-5-5 pending
- FIMKO Approval

Applications

- General Telecom Switching
- On/off Hook Control
 - Ring Delay
 - Dial Pulse
 - Ground Start
 - Ground Fault Protection
- Instrumentation
- Industrial Controls



Description

The LH1532 dual 1 Form A relays are SPST normally open switches that can replace electromechanical relays in many applications. They are constructed using a GaAlAs LED for actuation control and an integrated monolithic die for the switch output. The die, fabricated in a high-voltage dielectrically isolated technology is comprised of a photodiode array, switch control circuitry, and MOSFET switches. In addition, the LH1532 SSRs employ current-limiting circuitry, enabling them to pass FCC 68.302 and other regulatory surge requirements when overvoltage protection is provided.

Order Information

Part	Remarks
LH1532AAC	Tubes, SMD-8
LH1532AACTR	Tape and Reel, SMD-8
LH1532AB	Tubes, DIP-8

Absolute Maximum Ratings, $T_{amb} = 25\text{ }^{\circ}\text{C}$

Stresses in excess of the absolute Maximum Ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute Maximum Ratings for extended periods of time can adversely affect reliability.

SSR

Parameter	Test condition	Symbol	Value	Unit
LED continuous forward current		I_F	50	mA
LED reverse voltage	$I_R \leq 10\text{ }\mu\text{A}$	V_R	8.0	V
DC or peak AC load voltage	$I_L \leq 50\text{ }\mu\text{A}$	V_L	350	V
Continuous DC load current , one pole operating		I_L	120	mA
Continuous DC load current , two poles operating		I_L	110	mA
Peak load current (single shot)	$t = 100\text{ ms}$	I_P	2)	
Ambient temperature range		T_{amb}	- 40 to + 85	$^{\circ}\text{C}$
Storage temperature range		T_{stg}	- 40 to + 150	$^{\circ}\text{C}$
Pin soldering temperature	$t = 10\text{ s max}$	T_{sld}	260	$^{\circ}\text{C}$
Input/output isolation test voltage	$t = 1.0\text{ s}$	V_{ISO}	5300	V_{RMS}
Pole-to-pole isolation voltage (S1 to S2) ¹⁾ , (dry air, dust free, at sea level)			1600	V
Output power dissipation (continuous)		P_{diss}	600	mW

¹⁾ Breakdown occurs between the output pins external to the package.

²⁾ Refer to Current Limit Performance Application Note for a discussion relay operation during transient currents.

Electrical Characteristics, $T_{amb} = 25\text{ }^{\circ}\text{C}$

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

Input

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
LED forward current, switch turn-on	$I_L = 100\text{ mA}$, $t = 10\text{ ms}$	I_{Fon}		1.0	2.0	mA
LED forward current, switch turn-off	$V_L = \pm 300\text{ V}$	I_{Foff}	0.2	0.9		mA
LED forward voltage	$I_F = 10\text{ mA}$	V_F	1.15	1.26	1.45	V

Output

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
ON-resistance	$I_F = 5.0\text{ mA}$, $I_L = 50\text{ mA}$	R_{ON}	12	20	25	Ω
OFF-resistance	$I_F = 0\text{ mA}$, $V_L = \pm 100\text{ V}$	R_{OFF}	0.5	5000		$G\Omega$
Current limit	$I_F = 5.0\text{ mA}$, $t = 5.0\text{ ms}$, $V_L = \pm 6.0\text{ V}$	I_{LMT}	170	210	250	mA
Off-state leakage current	$I_F = 0\text{ mA}$, $V_L = \pm 100\text{ V}$	I_O		0.02	200	nA
	$I_F = 0\text{ mA}$, $V_L = \pm 350\text{ V}$	I_O			1.0	μA

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Output capacitance	$I_F = 0 \text{ mA}, V_L = 1.0 \text{ V}$	C_O		55		pF
	$I_F = 0 \text{ mA}, V_L = 50 \text{ V}$	C_O		10		pF
Pole-to-pole capacitance (S1 to S2)	$I_F = 5.0 \text{ mA}$			0.5		pF
Switch offset	$I_F = 5.0 \text{ mA}$	V_{OS}		0.15		V

Transfer

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Capacitance (input-output)	$V_{ISO} = 1.0 \text{ V}$	C_{IO}		1.1		pF
Turn-on time	$I_F = 5.0 \text{ mA}, I_L = 50 \text{ mA}$	t_{on}		1.4	2.5	ms
Turn-off time	$I_F = 5.0 \text{ mA}, I_L = 50 \text{ mA}$	t_{off}		0.7	2.5	ms

Typical Characteristics ($T_{amb} = 25 \text{ }^\circ\text{C}$ unless otherwise specified)

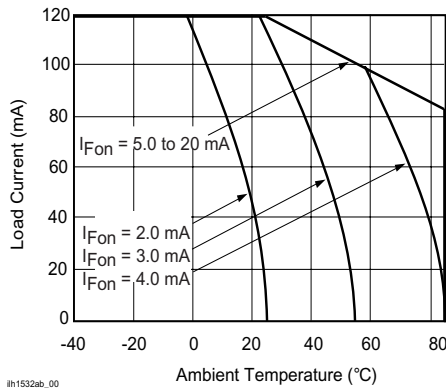


Figure 1. Recommended Operating Conditions

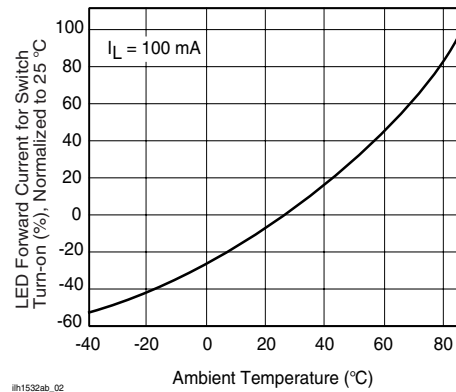


Figure 3. LED Current for Switch Turn-on vs. Temperature

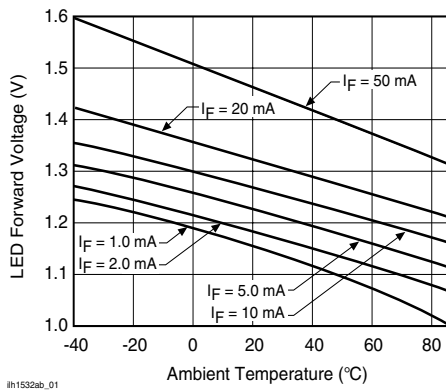


Figure 2. LED Voltage vs. Temperature

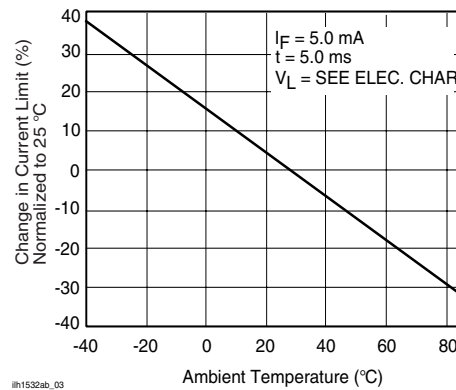
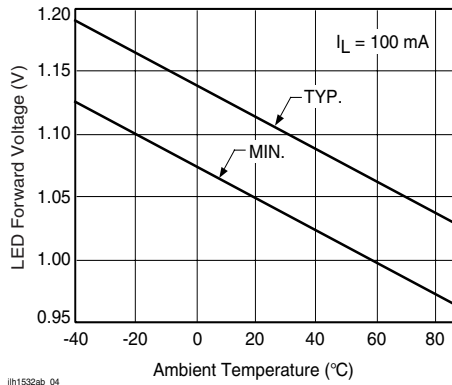
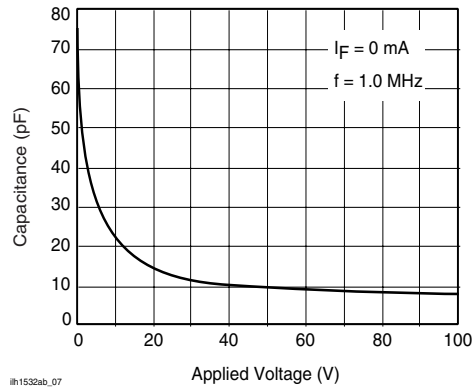


Figure 4. Current Limit vs. Temperature



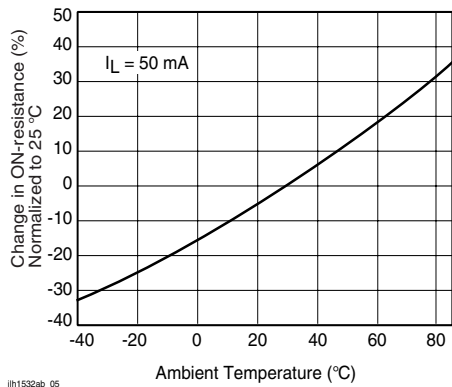
lh1532ab_04

Figure 5. LED Dropout Voltage vs. Temperature



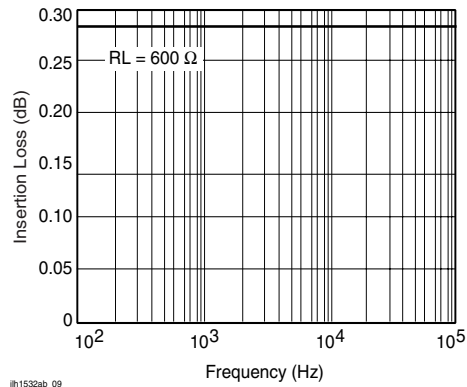
lh1532ab_07

Figure 8. Switch Capacitance vs. Applied Voltage



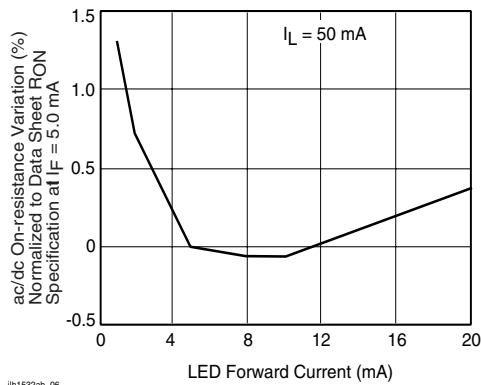
lh1532ab_05

Figure 6. ON-Resistance vs. Temperature



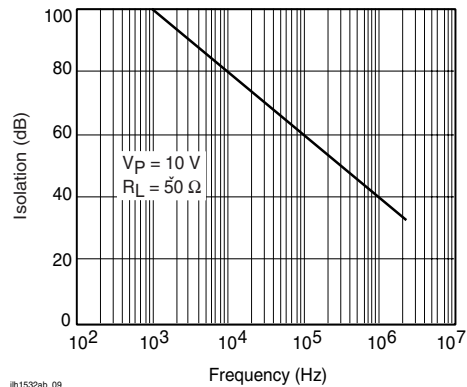
lh1532ab_09

Figure 9. Insertion Loss vs. Frequency



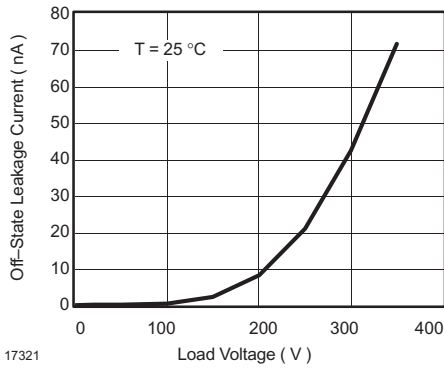
lh1532ab_06

Figure 7. Variation in ON-Resistance vs. LED Current



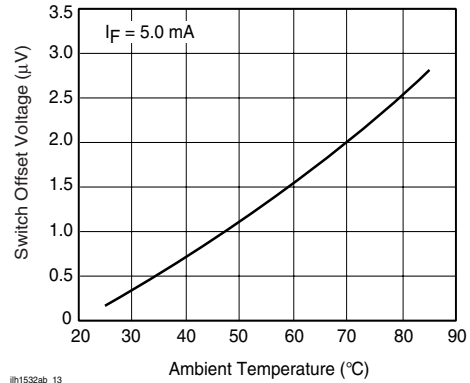
lh1532ab_09

Figure 10. Output Isolation



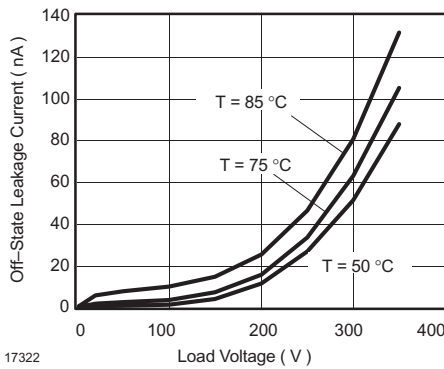
17321

Figure 11. Leakage Current vs. Applied Voltage



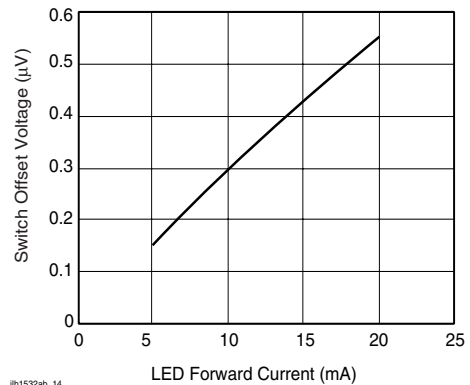
ih1532ab_13

Figure 14. Switch Offset Voltage vs. Temperature



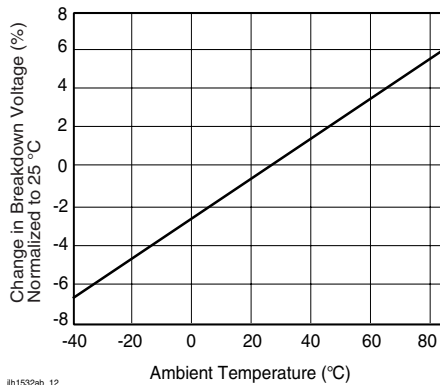
17322

Figure 12. Leakage Current vs. Applied Voltage at Elevated Temperatures



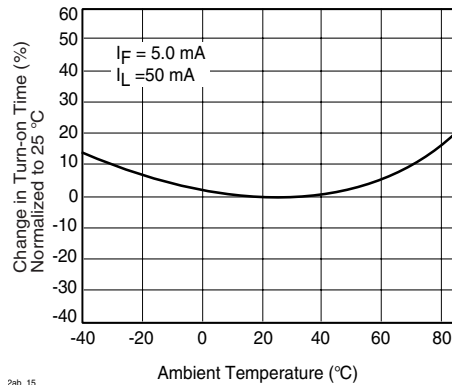
ih1532ab_14

Figure 15. Switch Offset Voltage vs. LED Current



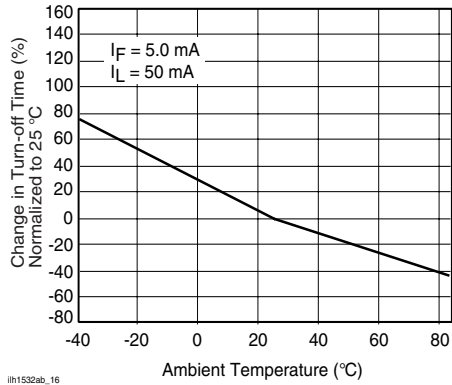
ih1532ab_12

Figure 13. Switch Breakdown Voltage vs. Temperature



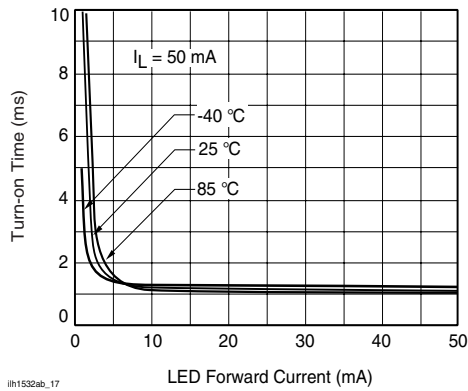
2ab_15

Figure 16. Turn-on Time vs. Temperature



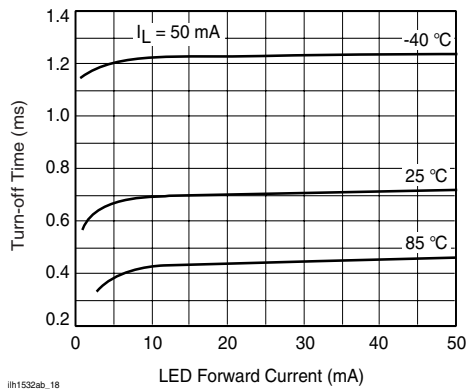
llh1532ab_16

Figure 17. Turn-off Time vs. Temperature



llh1532ab_17

Figure 18. Turn-on Time vs. LED Current

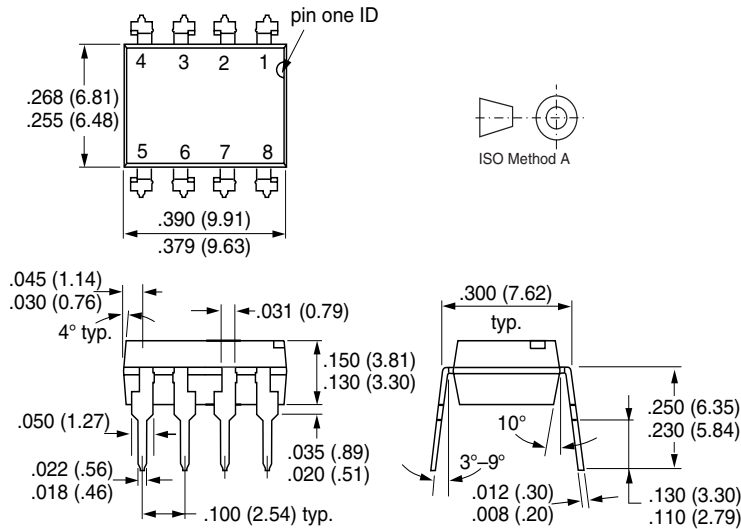


llh1532ab_18

Figure 19. Turn-off Time vs. LED Current

Package Dimensions in Inches (mm)

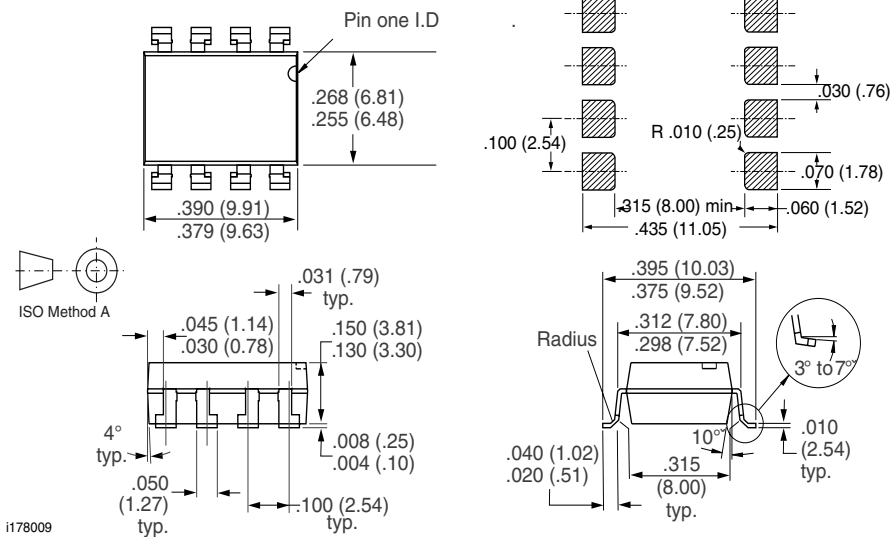
DIP



i178008

Package Dimensions in Inches (mm)

SMD



i178009

Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany
Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 67 2423



Notice

Specifications of the products displayed herein are subject to change without notice. Vishay Intertechnology, Inc., or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document. Except as provided in Vishay's terms and conditions of sale for such products, Vishay assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of Vishay products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Vishay for any damages resulting from such improper use or sale.